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What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Obsolete
Core Processor	F ² MC-16FX
Core Size	16-Bit
Speed	56MHz
Connectivity	CANbus, EBI/EMI, I ² C, LINbus, SCI, UART/USART
Peripherals	DMA, LVD, LVR, POR, PWM, WDT
Number of I/O	82
Program Memory Size	416KB (416K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 24x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	100-BQFP
Supplier Device Package	100-PQFP (14x20)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/mb96f347rsapqcr-gse2

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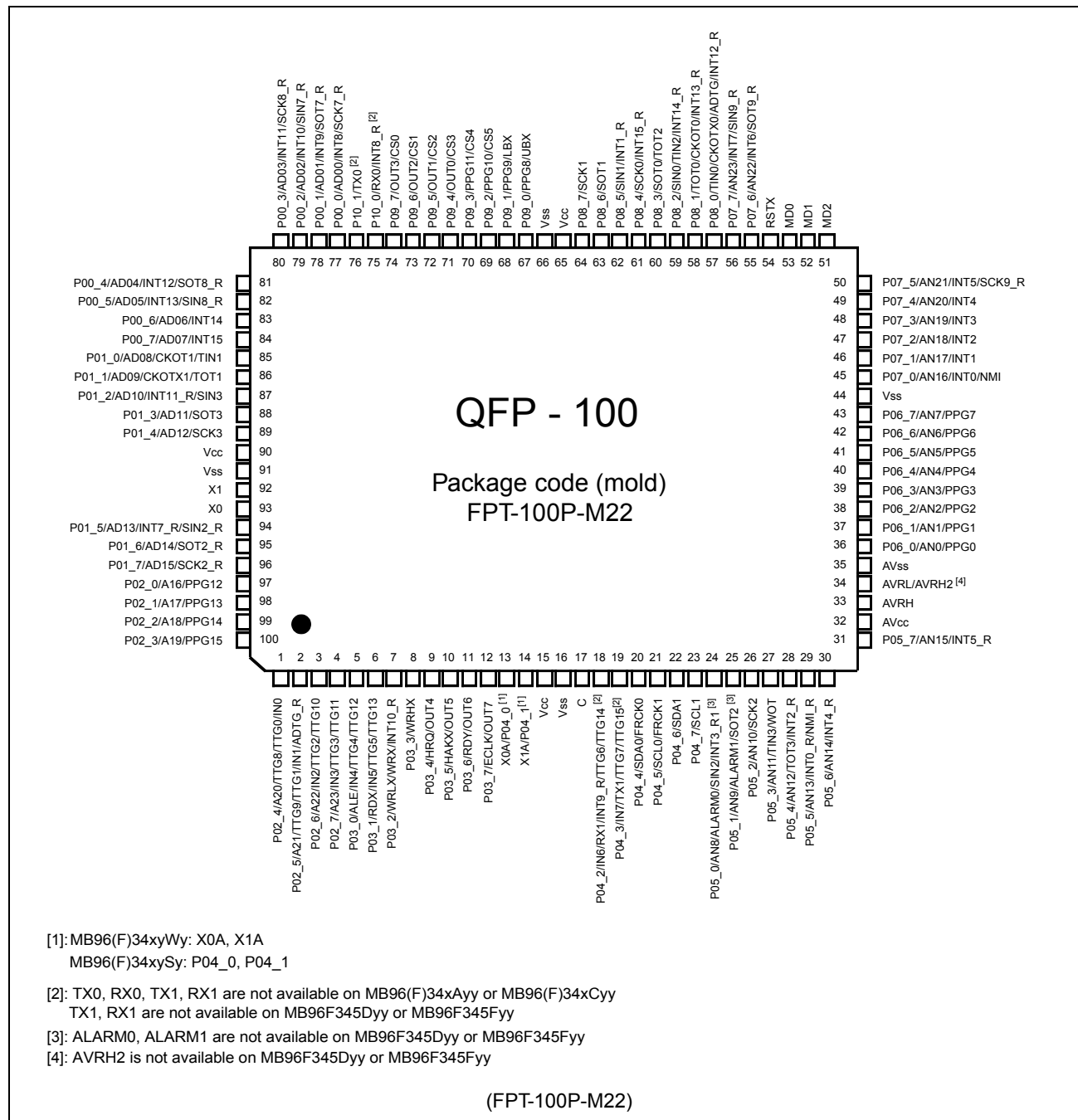
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Features	MB96V300B	MB96(F)34x
I ² C	2 channels	2 channels
A/D Converter	40 channels	24 channels
A/D Converter Reference Voltage switch	yes	yes (except MB96F345Dyy or MB96F345Fyy)
16-bit Reload Timer	6 channels + 1 channel (for PPG)	4 channels + 1 channel (for PPG)
16-bit Free-Running Timer	4 channels	2 channels
16-bit Output Compare	12 channels	8 channels
16-bit Input Capture	12 channels	8 channels
16-bit Programmable Pulse Generator	20 channels	16 channels
CAN Interface	5 channels	MB96(F)34xAyy or MB96(F)34xCyy: no MB96F345Dyy or MB96F345Fyy: 1 channel others: 2 channels
External Interrupts	16 channels	
Non-Maskable Interrupt	1 channel	
Real Time Clock	1	
I/O Ports	136	80 for part number with suffix "W", 82 for part number with suffix "S"
Alarm comparator	2 channels	MB96F345Dyy or MB96F345Fyy: no others: 2 channels
External bus interface	Yes	Yes (multiplexed address/data)
Chip select	6 signals	
Clock output function	2 channels	
Low voltage reset	Yes	
On-chip RC-oscillator	Yes	

[1]: These devices are under development and specification is preliminary. These products under development may change its specification without notice.

3. Pin Assignments

Figure 2. Pin assignment of MB96(F)34x (FPT-100P-M22)



[1]: MB96(F)34xyWy: X0A, X1A

MB96(F)34xySy: P04_0, P04_1

[2]: TX0, RX0, TX1, RX1 are not available on MB96(F)34xAyy or MB96(F)34xCyy
TX1, RX1 are not available on MB96F345Dyy or MB96F345Fyy

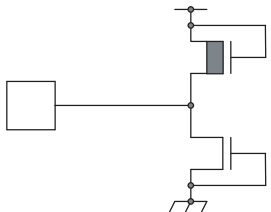
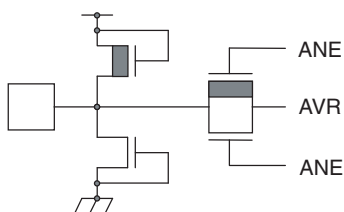
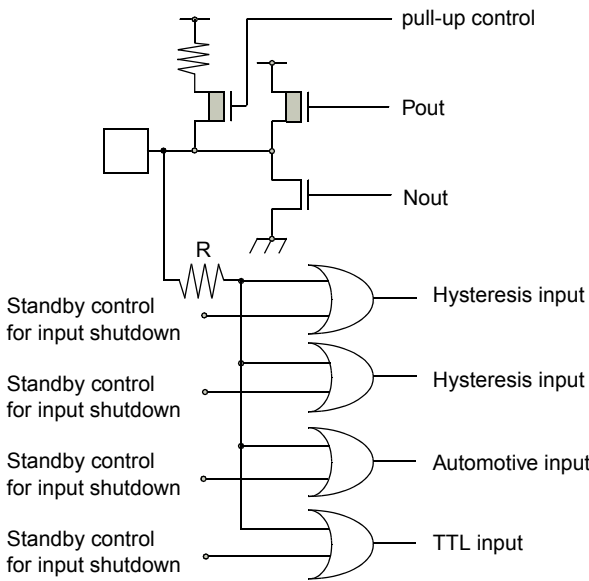
[3]: ALARM0, ALARM1 are not available on MB96F345Dyy or MB96F345Fyy

[4]: AVRH2 is not available on MB96F345Dyy or MB96F345Fyy

(FPT-100P-M22)

Remark:

MB96(F)34x products are pin-compatible to F²MC-16LX family MB90340 series.

Type	Circuit	Remarks
F		■ Power supply input protection circuit
G		■ A/D converter ref+ (AVRH/AVRH2) power supply input pin with protection circuit ■ Flash devices do not have a protection circuit against VCC for pins AVRH/AVRH2 ■ Devices without AVRH reference switch do not have an analog switch for the AVRL pin
H		■ CMOS level output (programmable $I_{OL} = 5\text{mA}$, $I_{OH} = -5\text{mA}$ and $I_{OL} = 2\text{mA}$, $I_{OH} = -2\text{mA}$) ■ 2 different CMOS hysteresis inputs with input shutdown function * ■ Automotive input with input shutdown function ■ TTL input with input shutdown function * ■ Programmable pull-up resistor: 50kΩ approx. *MB96F345Dyy or MB96F345Fyy: Only Automotive input and CMOS hysteresis input (0.7/0.3) are supported

7. Memory Map

MB96V300B			MB96(F)34x		
FF:FFFF _H	Emulation ROM		USER ROM / External Bus ^[4]		
DE:0000 _H					
	External Bus		External Bus		
10:0000 _H					
0F:E000 _H	Boot-ROM		Boot-ROM		
	Reserved	0F:0000 _H	Reserved		
0E:0000 _H			DATA FLASH / Reserved ^[4]		
	External RAM	0C:0000 _H	Reserved		
02:0000 _H			Reserved		
	Internal RAM bank 1	RAMEND1 ^[2] RAMSTART1 ^[2]	Internal RAM bank 1		RAM availability depending on the device
01:0000 _H			Reserved		
	ROM/RAM MIRROR		ROM/RAM MIRROR		
00:8000 _H					
	Internal RAM bank 0	RAMSTART0 ^[2]	Internal RAM bank 0		
			Reserved		
RAMSTART0 ^[3]			External Bus		External Bus end address ^[2]
00:0C00 _H	External Bus				
	Peripherals		Peripherals		
00:0380 _H					
00:0180 _H	GPR ^[1]		GPR ^[1]		
00:0100 _H	DMA		DMA		
00:00F0 _H	External Bus		External Bus		
00:0000 _H	Peripheral		Peripheral		

[1]: Unused GPR banks can be used as RAM area

[2]: For External Bus end address and RAMSTART/END addresses, please refer to the table on the next page.

[3]: For EVA device, RAMSTART0 depends on the configuration of the emulated device.

[4]: For details about USER ROM area or DATA FLASH area, see the [User ROM Memory Map For Flash Devices](#) and [User ROM Memory Map for Mask ROM Devices](#) on the following pages.

The External Bus area and DMA area are only available if the device contains the corresponding resource.

The available RAM and ROM area depends on the device.

Table 4: I/O map MB96(F)34x

Address	Register	Abbreviation 8-bit access	Abbreviation 16-bit access	Access
00002B _H	OCU0 - Compare Register			R/W
00002C _H	OCU1 - Compare Register		OCCP1	R/W
00002D _H	OCU1 - Compare Register			R/W
00002E _H	OCU2 - Output Compare Control Status	OCS2		R/W
00002F _H	OCU3 - Output Compare Control Status	OCS3		R/W
000030 _H	OCU2 - Compare Register		OCCP2	R/W
000031 _H	OCU2 - Compare Register			R/W
000032 _H	OCU3 - Compare Register		OCCP3	R/W
000033 _H	OCU3 - Compare Register			R/W
000034 _H	OCU4 - Output Compare Control Status	OCS4		R/W
000035 _H	OCU5 - Output Compare Control Status	OCS5		R/W
000036 _H	OCU4 - Compare Register		OCCP4	R/W
000037 _H	OCU4 - Compare Register			R/W
000038 _H	OCU5 - Compare Register		OCCP5	R/W
000039 _H	OCU5 - Compare Register			R/W
00003A _H	OCU6 - Output Compare Control Status	OCS6		R/W
00003B _H	OCU7 - Output Compare Control Status	OCS7		R/W
00003C _H	OCU6 - Compare Register		OCCP6	R/W
00003D _H	OCU6 - Compare Register			R/W
00003E _H	OCU7 - Compare Register		OCCP7	R/W
00003F _H	OCU7 - Compare Register			R/W
000040 _H	ICU0/ICU1 - Control Status Register	ICS01		R/W
000041 _H	ICU0/ICU1 - Edge register	ICE01		R/W
000042 _H	ICU0 - Capture Register Low	IPCPL0	IPCP0	R
000043 _H	ICU0 - Capture Register High	IPCPH0		R
000044 _H	ICU1 - Capture Register Low	IPCPL1	IPCP1	R
000045 _H	ICU1 - Capture Register High	IPCPH1		R
000046 _H	ICU2/ICU3 - Control Status Register	ICS23		R/W
000047 _H	ICU2/ICU3 - Edge register	ICE23		R/W
000048 _H	ICU2 - Capture Register Low	IPCPL2	IPCP2	R
000049 _H	ICU2 - Capture Register High	IPCPH2		R
00004A _H	ICU3 - Capture Register Low	IPCPL3	IPCP3	R

Table 4: I/O map MB96(F)34x

Address	Register	Abbreviation 8-bit access	Abbreviation 16-bit access	Access
000067 _H	RLT1 - Reload Register - for reading			R
000068 _H	RLT2 - Timer Control Status Register Low	TMCSRL2	TMCSR2	R/W
000069 _H	RLT2 - Timer Control Status Register High	TMCSRH2		R/W
00006A _H	RLT2 - Reload Register - for writing		TMRLR2	W
00006A _H	RLT2 - Reload Register - for reading		TMR2	R
00006B _H	RLT2 - Reload Register - for writing			W
00006B _H	RLT2 - Reload Register - for reading			R
00006C _H	RLT3 - Timer Control Status Register Low	TMCSRL3	TMCSR3	R/W
00006D _H	RLT3 - Timer Control Status Register High	TMCSRH3		R/W
00006E _H	RLT3 - Reload Register - for writing		TMRLR3	W
00006E _H	RLT3 - Reload Register - for reading		TMR3	R
00006F _H	RLT3 - Reload Register - for writing			W
00006F _H	RLT3 - Reload Register - for reading			R
000070 _H	RLT6 - Timer Control Status Register Low (dedic. RLT for PPG)	TMCSRL6	TMCSR6	R/W
000071 _H	RLT6 - Timer Control Status Register High (dedic. RLT for PPG)	TMCSRH6		R/W
000072 _H	RLT6 - Reload Register (dedic. RLT for PPG) - for writing		TMRLR6	W
000072 _H	RLT6 - Reload Register (dedic. RLT for PPG) - for reading		TMR6	R
000073 _H	RLT6 - Reload Register (dedic. RLT for PPG) - for writing			W
000073 _H	RLT6 - Reload Register (dedic. RLT for PPG) - for reading			R
000074 _H	PPG3-PPG0 - General Control register 1 Low	GCN1L0	GCN10	R/W
000075 _H	PPG3-PPG0 - General Control register 1 High	GCN1H0		R/W
000076 _H	PPG3-PPG0 - General Control register 2 Low	GCN2L0	GCN20	R/W
000077 _H	PPG3-PPG0 - General Control register 2 High	GCN2H0		R/W
000078 _H	PPG0 - Timer register		PTMR0	R
000079 _H	PPG0 - Timer register			R
00007A _H	PPG0 - Period setting register		PCSR0	W
00007B _H	PPG0 - Period setting register			W
00007C _H	PPG0 - Duty cycle register		PDUT0	W
00007D _H	PPG0 - Duty cycle register			W
00007E _H	PPG0 - Control status register Low	PCNL0	PCN0	R/W
00007F _H	PPG0 - Control status register High	PCNH0		R/W
000080 _H	PPG1 - Timer register		PTMR1	R

Table 4: I/O map MB96(F)34x

Address	Register	Abbreviation 8-bit access	Abbreviation 16-bit access	Access
000114 _H	DMA2 - I/O register address pointer low byte	IOAL2	IOA2	R/W
000115 _H	DMA2 - I/O register address pointer high byte	IOAH2		R/W
000116 _H	DMA2 - Data counter low byte	DCTL2	DCT2	R/W
000117 _H	DMA2 - Data counter high byte	DCTH2		R/W
000118 _H	DMA3 - Buffer address pointer low byte	BAPL3		R/W
000119 _H	DMA3 - Buffer address pointer middle byte	BAPM3		R/W
00011A _H	DMA3 - Buffer address pointer high byte	BAPH3		R/W
00011B _H	DMA3 - DMA control register	DMACS3		R/W
00011C _H	DMA3 - I/O register address pointer low byte	IOAL3	IOA3	R/W
00011D _H	DMA3 - I/O register address pointer high byte	IOAH3		R/W
00011E _H	DMA3 - Data counter low byte	DCTL3	DCT3	R/W
00011F _H	DMA3 - Data counter high byte	DCTH3		R/W
000120 _H	DMA4 - Buffer address pointer low byte	BAPL4		R/W
000121 _H	DMA4 - Buffer address pointer middle byte	BAPM4		R/W
000122 _H	DMA4 - Buffer address pointer high byte	BAPH4		R/W
000123 _H	DMA4 - DMA control register	DMACS4		R/W
000124 _H	DMA4 - I/O register address pointer low byte	IOAL4	IOA4	R/W
000125 _H	DMA4 - I/O register address pointer high byte	IOAH4		R/W
000126 _H	DMA4 - Data counter low byte	DCTL4	DCT4	R/W
000127 _H	DMA4 - Data counter high byte	DCTH4		R/W
000128 _H	DMA5 - Buffer address pointer low byte	BAPL5		R/W
000129 _H	DMA5 - Buffer address pointer middle byte	BAPM5		R/W
00012A _H	DMA5 - Buffer address pointer high byte	BAPH5		R/W
00012B _H	DMA5 - DMA control register	DMACS5		R/W
00012C _H	DMA5 - I/O register address pointer low byte	IOAL5	IOA5	R/W
00012D _H	DMA5 - I/O register address pointer high byte	IOAH5		R/W
00012E _H	DMA5 - Data counter low byte	DCTL5	DCT5	R/W
00012F _H	DMA5 - Data counter high byte	DCTH5		R/W
000130 _H -00017F _H	Reserved			-
000180 _H -00037F _H	CPU - General Purpose registers (RAM access)	GPR_RAM		R/W
000380 _H	DMA0 - Interrupt select	DISEL0		R/W
000381 _H	DMA1 - Interrupt select	DISEL1		R/W

Table 4: I/O map MB96(F)34x

Address	Register	Abbreviation 8-bit access	Abbreviation 16-bit access	Access
0003D9 _H	Memory Patch function - Patch data 4 High	PFDH4		R/W
0003DA _H	Memory Patch function - Patch data 5 Low	PFDL5	PFD5	R/W
0003DB _H	Memory Patch function - Patch data 5 High	PFDH5		R/W
0003DC _H	Memory Patch function - Patch data 6 Low	PFDL6	PFD6	R/W
0003DD _H	Memory Patch function - Patch data 6 High	PFDH6		R/W
0003DE _H	Memory Patch function - Patch data 7 Low	PFDL7	PFD7	R/W
0003DF _H	Memory Patch function - Patch data 7 High	PFDH7		R/W
0003E0 _H	Data Flash Control and Status register A	DFCSA		R/W
0003E1 _H	Data Flash Write command sequencer Control register A	DFWCA		R/W
0003E2 _H	Data Flash Write command sequencer Status register A	DFWSA		R/W
0003E3 _H -0003F0 _H	Reserved			-
0003F1 _H	Memory Control Status Register A	MCSRA		R/W
0003F2 _H	Memory Timing Configuration Register A Low	MTCRAL	MTCRA	R/W
0003F3 _H	Memory Timing Configuration Register A High	MTCRAH		R/W
0003F4 _H	Reserved			-
0003F5 _H	Memory Control Status Register B	MCSRBA		R/W
0003F6 _H	Memory Timing Configuration Register B Low	MTCRBL	MTCRB	R/W
0003F7 _H	Memory Timing Configuration Register B High	MTCRBH		R/W
0003F8 _H	Flash Memory Write Control register 0	FMWC0		R/W
0003F9 _H	Flash Memory Write Control register 1	FMWC1		R/W
0003FA _H	Flash Memory Write Control register 2	FMWC2		R/W
0003FB _H	Flash Memory Write Control register 3	FMWC3		R/W
0003FC _H	Flash Memory Write Control register 4	FMWC4		R/W
0003FD _H	Flash Memory Write Control register 5	FMWC5		R/W
0003FE _H -0003FF _H	Reserved			-
000400 _H	Standby Mode control register	SMCR		R/W
000401 _H	Clock select register	CKSR		R/W
000402 _H	Clock Stabilization select register	CKSSR		R/W
000403 _H	Clock monitor register	CKMR		R
000404 _H	Clock Frequency control register Low	CKFCRL	CKFCR	R/W
000405 _H	Clock Frequency control register High	CKFCRH		R/W
000406 _H	PLL Control register Low	PLLCRL	PLLCR	R/W

Table 4: I/O map MB96(F)34x

Address	Register	Abbreviation 8-bit access	Abbreviation 16-bit access	Access
0006EB _H	External Bus - Area configuration register 5 High	EACH5		R/W
0006EC _H	External Bus - Area select register 2	EAS2		R/W
0006ED _H	External Bus - Area select register 3	EAS3		R/W
0006EE _H	External Bus - Area select register 4	EAS4		R/W
0006EF _H	External Bus - Area select register 5	EAS5		R/W
0006F0 _H	External Bus - Mode register	EBM		R/W
0006F1 _H	External Bus - Clock and Function register	EBCF		R/W
0006F2 _H	External Bus - Address output enable register 0	EBAE0		R/W
0006F3 _H	External Bus - Address output enable register 1	EBAE1		R/W
0006F4 _H	External Bus - Address output enable register 2	EBAE2		R/W
0006F5 _H	External Bus - Control signal register	EBCS		R/W
0006F6 _H -0006FF _H	Reserved			-
000700 _H	CAN0 - Control register Low	CTRLRL0	CTRLR0	R/W
000701 _H	CAN0 - Control register High (reserved)	CTRLRH0		R
000702 _H	CAN0 - Status register Low	STATRL0	STATR0	R/W
000703 _H	CAN0 - Status register High (reserved)	STATRH0		R
000704 _H	CAN0 - Error Counter Low (Transmit)	ERRCNTL0	ERRCNT0	R
000705 _H	CAN0 - Error Counter High (Receive)	ERRCNTH0		R
000706 _H	CAN0 - Bit Timing Register Low	BTRL0	BTR0	R/W
000707 _H	CAN0 - Bit Timing Register High	BTRH0		R/W
000708 _H	CAN0 - Interrupt Register Low	INTRL0	INTR0	R
000709 _H	CAN0 - Interrupt Register High	INTRH0		R
00070A _H	CAN0 - Test Register Low	TESTRL0	TESTR0	R/W
00070B _H	CAN0 - Test Register High (reserved)	TESTRH0		R
00070C _H	CAN0 - BRP Extension register Low	BRPERL0	BRPER0	R/W
00070D _H	CAN0 - BRP Extension register High (reserved)	BRPERH0		R
00070E _H -00070F _H	Reserved			-
000710 _H	CAN0 - IF1 Command request register Low	IF1CREQL0	IF1CREQ0	R/W
000711 _H	CAN0 - IF1 Command request register High	IF1CREQH0		R/W
000712 _H	CAN0 - IF1 Command Mask register Low	IF1CMSKL0	IF1CMSK0	R/W
000713 _H	CAN0 - IF1 Command Mask register High (reserved)	IF1CMSKH0		R
000714 _H	CAN0 - IF1 Mask 1 Register Low	IF1MSK1L0	IF1MSK10	R/W

13. Handling Devices

Special care is required for the following when handling the device:

- Latch-up prevention
- Unused pins handling
- External clock usage
- Unused sub clock signal
- Notes on PLL clock mode operation
- Power supply pins (V_{CC}/V_{SS})
- Crystal oscillator circuit
- Turn on sequence of power supply to A/D converter and analog inputs
- Pin handling when not using the A/D converter
- Notes on energization
- Stabilization of power supply voltage
- Serial communication
- Handling of Data Flash

13.1 Latch-up prevention

CMOS IC chips may suffer latch-up under the following conditions:

- A voltage higher than V_{CC} or lower than V_{SS} is applied to an input or output pin.
- A voltage higher than the rated voltage is applied between V_{CC} pins and V_{SS} pins.
- The AV_{CC} power supply is applied before the V_{CC} voltage.

Latch-up may increase the power supply current dramatically, causing thermal damages to the device.

For the same reason, extra care is required to not let the analog power-supply voltage (AV_{CC} , $AVRH$) exceed the digital power-supply voltage.

13.2 Unused pins handling

Unused input pins can be left open when the input is disabled (corresponding bit of Port Input Enable register $PIER = 0$).

Leaving unused input pins open when the input is enabled may result in misbehavior and possible permanent damage of the device. They must therefore be pulled up or pulled down through resistors. To prevent latch-up, those resistors should be more than 2 k Ω .

Unused bidirectional pins can be set either to the output state and be then left open, or to the input state with either input disabled or external pull-up/pull-down resistor as described above.

13.3 External clock usage

The permitted frequency range of an external clock depends on the oscillator type and configuration. See [AC Characteristics](#) for detailed modes and frequency limits. Single and opposite phase external clocks must be connected as follows:

Parameter	Symbol	Rating		Unit	Remarks
		Min	Max		
Permitted Power dissipation (Mask ROM devices) ^[4]	P_D	-	350	mW	$T_A=105^{\circ}\text{C}$
		-	360	mW	$T_A=125^{\circ}\text{C}$ [6]
Operating ambient temperature	T_A	0	+70	$^{\circ}\text{C}$	MB96V300B
		-40	+105		
		-40	+125		[6]
Storage temperature	T_{STG}	-55	+150	$^{\circ}\text{C}$	

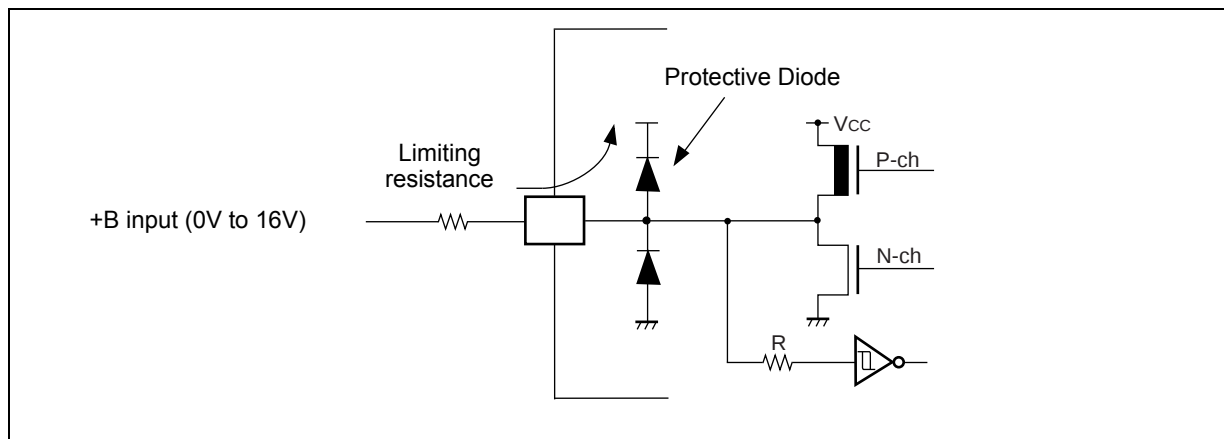
[1]: AV_{CC} and V_{CC} must be set to the same voltage. It is required that AV_{CC} does not exceed V_{CC} and that the voltage at the analog inputs does not exceed AV_{CC} neither when the power is switched on.

[2]: V_I and V_O should not exceed $V_{CC} + 0.3\text{ V}$. V_I should also not exceed the specified ratings. However if the maximum current to/from a input is limited by some means with external components, the I_{CLAMP} rating supersedes the V_I rating. Input/output voltages of standard ports depend on V_{CC} .

[3]:

- Applicable to all general purpose I/O pins (Pnn_m)
- Use within recommended operating conditions.
- Use at DC voltage (current)
- The +B signal should always be applied a limiting resistance placed between the +B signal and the microcontroller.
- The value of the limiting resistance should be set so that when the +B signal is applied the input current to the microcontroller pin does not exceed rated values, either instantaneously or for prolonged periods.
- Note that when the microcontroller drive current is low, such as in the power saving modes, the +B input potential may pass through the protective diode and increase the potential at the V_{CC} pin, and this may affect other devices.
- Note that if a +B signal is input when the microcontroller power supply is off (not fixed at 0 V), the power supply is provided from the pins, so that incomplete operation may result.
- Note that if the +B input is applied during power-on, the power supply is provided from the pins and the resulting supply voltage may not be sufficient to operate the Power reset (except devices with persistent low voltage reset in internal vector mode).

Sample recommended circuits:



($T_A = -40^{\circ}\text{C}$ to 125°C , $V_{CC} = AV_{CC} = 3.0\text{V}$ to 5.5V , $V_{SS} = AV_{SS} = 0\text{V}$)

Parameter	Symbol	Condition (at T_A)		Value			Remarks
				Typ	Max	Unit	
Power supply current in Run modes ^[1]	I_{CCRCH}	RC Run mode with $CLKS1/2 = CLKB = CLKP1/2 = 2\text{MHz}$ (CLKMC, CLKPLL and CLKSC stopped)	+25°C	2.9	4	mA	Flash devices at 1 Flash wait state
			+125°C	3.5	6.5		
			+25°C	1.7	2.7	mA	MB96345/346 at 1 ROM wait state
			+125°C	2.3	4.7		
	I_{CCRCL}	RC Run mode with $CLKS1/2 = CLKB = CLKP1/2 = 100\text{kHz}$, SMCR:LPMS = 0 (CLKMC, CLKPLL and CLKSC stopped. Voltage regulator in high power mode)	+25°C	0.4	0.6	mA	MB96F346/F347/F348 at 1 Flash wait state
			+125°C	0.9	3.5		
			+25°C	0.18	0.3	mA	MB96F345 at 1 Flash wait state
			+125°C	0.68	3.3		
			+25°C	0.4	0.6	mA	MB96345/346 at 1 ROM wait state
			+125°C	0.9	2.4		
		RC Run mode with $CLKS1/2 = CLKB = CLKP1/2 = 100\text{kHz}$, SMCR:LPMS = 1 (CLKMC, CLKPLL and CLKSC stopped. Voltage regulator in low power mode, no Flash programming/erasing allowed)	+25°C	0.15	0.25	mA	Flash devices at 1 Flash wait state
			+125°C	0.65	3.2		
			+25°C	0.15	0.25	mA	MB96345/346 at 1 ROM wait state
			+125°C	0.65	2.1		
	I_{CCSUB}	Sub Run mode with $CLKS1/2 = CLKB = CLKP1/2 = 32\text{kHz}$ (CLKMC, CLKPLL and CLKRC stopped, no Flash programming/erasing allowed)	+25°C	0.1	0.2	mA	Flash devices at 1 Flash wait state
			+125°C	0.6	3		
			+25°C	0.1	0.2	mA	MB96345/346 at 1 ROM wait state
			+125°C	0.6	2		

14.4.7 Basic Timing

($T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $V_{CC} = 5.0\text{ V} \pm 10\%$, $V_{SS} = 0.0\text{ V}$, $I_{O_{drive}} = 5\text{mA}$, $C_L = 50\text{pF}$)

Parameter	Symbol	Pin	Condition	Value		Unit	Remarks
				Min	Max		
ECLK	t_{CYC}	ECLK	-	25	-	ns	
	t_{CHCL}			$t_{CYC}/2-5$	$t_{CYC}/2+5$		
	t_{CLCH}			$t_{CYC}/2-5$	$t_{CYC}/2+5$		
ECLK → UBX/ LBX / CSn time	t_{CHCBH}	CSn, UBX, LBX, ECLK	-	-20	20	ns	
	t_{CHCBL}			-20	20		
	t_{CLCBH}			-20	20		
	t_{CLCBL}			-20	20		
ECLK → ALE time	t_{CHLH}	ALE, ECLK	-	-10	10	ns	
	t_{CHLL}			-10	10		
	t_{CLLH}			-10	10		
	t_{CLLL}			-10	10		
ECLK → address valid time	t_{CHAV}	A[23:16], ECLK	-	-15	15	ns	
	t_{CLAV}			-15	15		
	t_{CLADV}	AD[15:0], ECLK	-	-15	15	ns	
	t_{CHADV}			-15	15		
ECLK → RDX /WRX time	t_{CHRWL}	RDX, WRX, WRLX, WRHX, ECLK	-	-10	10	ns	
	t_{CHRWL}			-10	10		
	t_{CLRWH}			-10	10		
	t_{CLRWL}			-10	10		

($T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $V_{CC} = 3.0$ to 4.5V , $V_{SS} = 0.0\text{V}$, $I_{Odrive} = 5\text{mA}$, $C_L = 50\text{pF}$)

Parameter	Symbol	Pin	Conditions	Value		Unit	Remarks
				Min	Max		
Valid address $\Rightarrow$ Valid data input	t_{AVDV}	A[23:16], AD[15:0]	EACL:ACE=0	-	$3t_{CYC} - 60$	ns	w/o cycle extension
			EACL:ACE=1	-	$4t_{CYC} - 60$		
	$t_{ADV DV}$	AD[15:0]	EACL:ACE=0	-	$5t_{CYC}/2 - 60$	ns	w/o cycle extension
			EACL:ACE=1	-	$7t_{CYC}/2 - 60$		
RDX pulse width	t_{RLRH}	RDX	-	$3t_{CYC}/2 - 8$	-	ns	w/o cycle extension
RDX $\downarrow \Rightarrow$ Valid data input	t_{RLDV}	RDX, AD[15:0]	-	-	$3t_{CYC}/2 - 55$	ns	w/o cycle extension
RDX $\uparrow \Rightarrow$ Data hold time	t_{RHDX}	RDX, AD[15:0]	-	0	-	ns	
Address valid $\Rightarrow$ Data hold time	t_{AXDX}	A[23:16]	-	0	-	ns	
RDX $\uparrow \Rightarrow$ ALE $\uparrow$ time	t_{RHLH}	RDX, ALE	EACL:STS=1 and EACL:ACE=1	$3t_{CYC}/2 - 15$	-	ns	
			other ECL:STS, EA-CL:ACE setting	$t_{CYC}/2 - 15$	-		
Valid address $\Rightarrow$ ECLK $\uparrow$ time	t_{AVCH}	A[23:16], ECLK	-	$t_{CYC} - 20$	-	ns	
	t_{ADVCH}	AD[15:0], ECLK		$t_{CYC}/2 - 20$	-		
RDX $\downarrow \Rightarrow$ ECLK $\uparrow$ time	t_{RLCH}	RDX, ECLK	-	$t_{CYC}/2 - 15$	-	ns	
ALE $\downarrow \Rightarrow$ RDX $\downarrow$ time	t_{LLRL}	ALE, RDX	EACL:STS=0	$t_{CYC}/2 - 15$	-	ns	
			EACL:STS=1	- 15	-		
ECLK $\uparrow \Rightarrow$ Valid data input	t_{CHDV}	AD[15:0], ECLK	-	-	$t_{CYC} - 55$	ns	

14.4.9 Bus Timing (Write)

($T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $V_{CC} = 5.0\text{ V} \pm 10\%$, $V_{SS} = 0.0\text{ V}$, $I_{O\text{drive}} = 5\text{mA}$, $C_L = 50\text{pF}$)

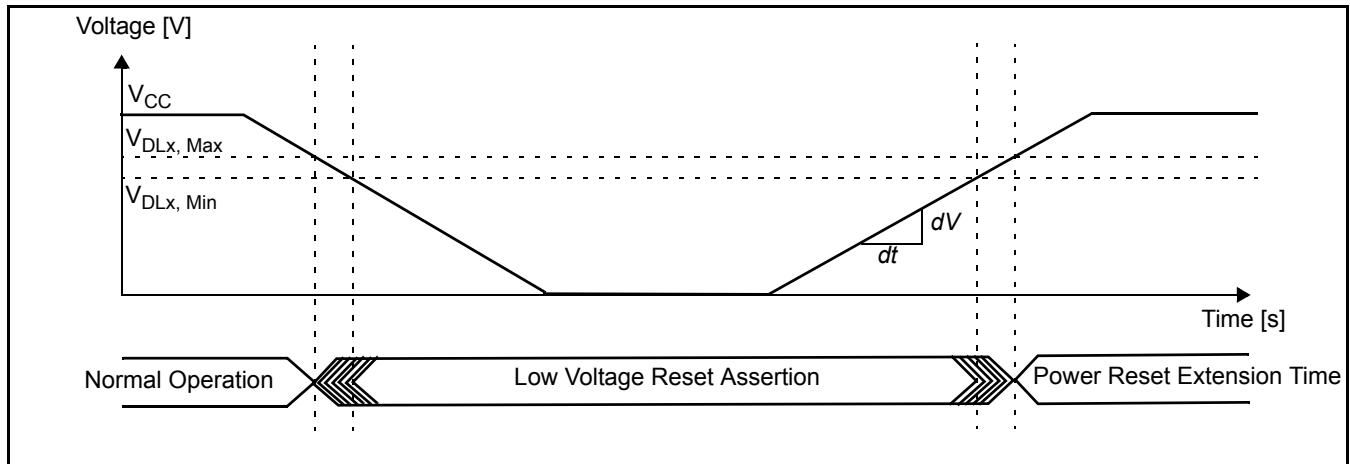
Parameter	Symbol	Pin	Condition	Value		Unit	Remarks
				Min	Max		
Valid address $\Rightarrow$ WRX $\downarrow$ time	t_{AVWL}	WRX, WRLX, WRHX, A[23:16]	EACL:ACE=0	$3t_{\text{CYC}}/2 - 15$	-	ns	
			EACL:ACE=1	$5t_{\text{CYC}}/2 - 15$	-		
	t_{ADVWL}	WRX, WRLX, WRHX, AD[15:0]	EACL:ACE=0	$t_{\text{CYC}} - 15$	-	ns	
			EACL:ACE=1	$2t_{\text{CYC}} - 15$	-		
WRX pulse width	t_{WLWH}	WRX, WRLX, WRHX	-	$t_{\text{CYC}} - 5$	-	ns	w/o cycle extension
Valid data output $\Rightarrow$ WRX $\uparrow$ time	t_{DVWH}	WRX, WRLX, WRHX, AD[15:0]	-	$t_{\text{CYC}} - 20$	-	ns	w/o cycle extension
WRX $\uparrow \Rightarrow$ Data hold time	t_{WHDX}	WRX, WRLX, WRHX, AD[15:0]	-	$t_{\text{CYC}}/2 - 15$	-	ns	
WRX $\uparrow \Rightarrow$ Address valid time	t_{WHAX}	WRX, WRLX, WRHX, A[23:16]	-	$t_{\text{CYC}}/2 - 15$	-	ns	
WRX $\uparrow \Rightarrow$ ALE $\uparrow$ time	t_{WHLH}	WRX, WRLX, WRHX, ALE	EBM:ACE=1 and EACL:STS=1	$2t_{\text{CYC}} - 10$	-	ns	
			other EBM:ACE and EACL:STS setting	$t_{\text{CYC}} - 10$	-		
WRX $\downarrow \Rightarrow$ ECLK $\uparrow$ time	t_{WLCH}	WRX, WRLX, WRHX, ECLK	-	$t_{\text{CYC}}/2 - 10$	-	ns	
CSn $\Rightarrow$ WRX time	t_{CSLWL}	WRX, WRLX, WRHX, CSn	EACL:ACE=0	-	$3t_{\text{CYC}}/2 - 15$	ns	
			EACL:ACE=1	-	$5t_{\text{CYC}}/2 - 15$		
WRX $\Rightarrow$ CSn time	t_{WHCSH}	WRX, WRLX, WRHX, CSn	-	$t_{\text{CYC}}/2 - 15$	-	ns	

($T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $V_{CC} = 3.0$ to 4.5V , $V_{SS} = 0.0\text{ V}$, $I_{O\text{drive}} = 5\text{mA}$, $C_L = 50\text{pF}$)

Parameter	Symbol	Pin	Condition	Value		Unit	Remarks
				Min	Max		
Valid address $\Rightarrow$ WRX $\downarrow$ time	t_{AVWL}	WRX, WRLX, WRHX, A[23:16]	EACL:ACE=0	$3t_{\text{CYC}}/2 - 20$	-	ns	
			EACL:ACE=1	$5t_{\text{CYC}}/2 - 20$	-		
	t_{ADVWL}	WRX, WRLX, WRHX, AD[15:0]	EACL:ACE=0	$t_{\text{CYC}} - 20$	-	ns	
			EACL:ACE=1	$2t_{\text{CYC}} - 20$	-		

14.7.1 Low Voltage Detector Operation

In the following figure, the occurrence of a low voltage condition is illustrated. For a detailed description of the reset and startup behavior, please refer to the corresponding hardware manual chapter.



14.8 Flash Memory Program/erase Characteristics

($T_A = -40^{\circ}\text{C}$ to 105°C , $V_{CC} = AV_{CC} = 3.0\text{V}$ to 5.5V , $V_{SS} = AV_{SS} = 0\text{V}$)

Parameter	Value			Unit	Remarks
	Min	Typ	Max		
Sector erase time Program/Data Flash (Main Flash)	-	0.9	3.6	s	Without erasure pre-programming time
Sector erase time Data Flash	-	0.5	2	s	Without erasure pre-programming time
	-	0.8	3.6	s	Including erasure pre-programming time
Chip erase time Program/Data Flash (Main Flash)	-	n*0.9	n*3.6	s	Without erasure pre-programming time (n is the number of Flash sector of the device)
Chip erase time Data Flash	-	2.5	10	s	Without erasure pre-programming time
	-	3.7	16.4	s	Including erasure pre-programming time
Word (16-bit width) programming time Program/Data Flash (Main Flash)	-	23	370	us	Without overhead time for submitting write command
Byte (8-bit width) programming time Data Flash	-	15	100	us	Without overhead time for submitting write command
Program/Erase cycle	10000	-	-	cycle	100 000 Program/Erase cycles are under evaluation by Cypress
Flash data retention time	20	-	-	year	[1]

[1]: This value was converted from the results of evaluating the reliability of the technology (using Arrhenius equation to convert high temperature measurements into normalized value at 85°C)

18.1 MCU with CAN Controller

Part number	Flash/ROM	Subclock	Persistent Low Voltage Reset	Package
MB96F347YSB PQC-GSE2	Flash A (416KB)	No	Yes	100 pin Plastic QFP (FPT-100P-M22)
MB96F347RSB PQC-GSE2			No	
MB96F347YWB PQC-GSE2		Yes	Yes	
MB96F347RWB PQC-GSE2			No	
MB96F347YSB PMC-GSE2		No	Yes	100 pin Plastic LQFP (FPT-100P-M20)
MB96F347RSB PMC-GSE2			No	
MB96F347YWB PMC-GSE2		Yes	Yes	
MB96F347RWB PMC-GSE2			No	
MB96F348YSB PQC-GSE2	Flash A (544KB)	No	Yes	100 pin Plastic QFP (FPT-100P-M22)
MB96F348RSB PQC-GSE2			No	
MB96F348YWB PQC-GSE2		Yes	Yes	
MB96F348RWB PQC-GSE2			No	
MB96F348YSB PMC-GSE2		No	Yes	100 pin Plastic LQFP (FPT-100P-M20)
MB96F348RSB PMC-GSE2			No	
MB96F348YWB PMC-GSE2		Yes	Yes	
MB96F348RWB PMC-GSE2			No	
MB96F348TSC PQC-GSE2	Flash A (544KB) Flash B (32KB)	No	Yes	100 pin Plastic QFP (FPT-100P-M22)
MB96F348HSC PQC-GSE2			No	
MB96F348TWC PQC-GSE2		Yes	Yes	
MB96F348HWC PQC-GSE2			No	
MB96F348TSC PMC-GSE2		No	Yes	100 pin Plastic LQFP (FPT-100P-M20)
MB96F348HSC PMC-GSE2			No	
MB96F348TWC PMC-GSE2		Yes	Yes	
MB96F348HWC PMC-GSE2			No	
MB96V300BRB-ES(for evaluation)	Emulated by ext. RAM	Yes	No	416 pin Plastic BGA (BGA-416P-M02)

19. Revision History

Revision	Date	Modification
Prelim 1	2007-05-07	Creation
Prelim 2	2007-05-10	External bus hold timing update
Prelim 3	2007-05-23	Electrical characteristics updates
Prelim 4	2007-08-02	Electrical characteristics updates, Product lineup, changes and ordering information
Prelim 5	2007-09-12	Addition of the electrical characteristic examples and the LVD characteristics specifications, updates of the DC characteristics. Pin circuit type drawing modifications.
Prelim 6	2007-11-21	LVD typo correction. Update of the DC characteristics. Typos corrections.
Prelim 7	2007-12-04	Absolute maximum rating asterisks numbering corrected. Typos page 59: Hardware -> Hardware. IO map table regenerated. Typos corrections. IO circuit drawings modified. Renaming of the Main/Satellite Flash into Flash memory A/B. Memory map reworked.
Prelim 8	2008-02-04	■ Satellite Flash -> 32kB Data Flash ■ MB96345 added (under development) ■ MB96F348 TSA/HSA/TWA/HWA removed (outdated devices) ■ Block diagram and pin assignment corrected (existing resource pins) ■ Pin function table corrected ■ I/O circuit type diagrams corrected ■ Memory map cleaned up ■ "Flash sector configuration" replaced by corrected "User ROM Memory map for Flash devices", "ROM configuration" replaced by "User ROM Memory map for Mask ROM devices" ■ Parallel Flash programming pinning removed ■ IO map table regenerated: □ Port register: Naming style corrected □ Memory control registers renamed (Main/Sat -> A/B) □ addresses after 000BFFh removed ■ Absolute maximum ratings: Pd and Ta specified more precisely ■ oscillator input levels in oscillation mode with external clock added ■ Run and Sleep mode currents: 96/48MHz and 72/36MHz settings added ■ Run mode current spec in 48/24MHz mode corrected ■ Maximum CLKS1/2 frequency for all devices correctly specified ■ Maximum CLKP2 for MB96F34xY/R/Axx corrected ■ External bus timings: missing conditions added and readability improved ■ Alarm comparator spec updated (transition voltages defined) ■ MB96V300A removed ■ Ordering information updated ■ Typos and formatting corrected